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Comment on two papers claiming records for the lowest carrier concentration at which superconductivity has been observed

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A 2013 paper [1] and a recent preprint [2] claim records for the lowest carrier concentrations at which superconductivity has been observed, at concentrations of 5.5×10^{17} cm^{-3} in a crystal of $SrTiO_3$ [1] and 3×10^{17} cm^{-3} in a crystal of Bi [2]. However, evidence for superconductivity at much lower carrier concentrations at low-temperatures, of the order of 10^{15} cm^{-3}, was obtained by myself and colleagues in the late 1980's [3, 4, 5] in a reduced ceramic sample of $SrTiO_3$ with 3% of Ti replaced by Zr. The Zr does not produce any charge carriers, but does produce large increases in their effective mass [7], as shown by analysis of magnetic-field penetration depth results of Hulm et al [8]. The increase in mass appears to be sufficient to increase the electron-phonon coupling above the threshold at which pairing without superconductivity at very low carrier concentrations is possible [9].

We were unable to measure the low-temperature Hall coefficients in the ceramic samples studied, and so had to infer the low-temperature carrier concentrations, n, indirectly. However, two different methods [4, 5] gave results in agreement with each other. The first method was based on inferences from room-temperature Hall measurements and resistivities as a function of temperature about which side of the maximum in T_c versus carrier concentration the six superconducting samples lay, and approximately where, and led to an estimate that 3×10^{14} cm^{-3} $< n < 5\times10^{15}$ cm^{-3} for the sample mentioned. The second method was based on detailed analysis of the resistivity between 4.2 K and 75 mK, and resulted in an estimate of $n \approx 3\times10^{14}$ cm $^{-3}$, at the lower end of the previous estimate. There was a temperature range between 130 mK and 75 mK in which pairing without superconductivity raised the resistance above what it would have been with no pairing. These low carrier concentrations and analysis showed that we were in the Bose-Einstein condensation régime in this sample. The results were in qualitative, but not quantitative, agreement to predictions made by me in 1969 [9].

Later we examined two macrocrystalline samples [6], but in these samples some non-uniform states appeared to prevent our reaching the Bose-condensation regime. We did find a sharp drop in resistance at about 600 mK in both samples, one of which had an average concentration at 2.3 K of about 5×10^{15} cm^{-3}. The drops in resistance were probably due to small superconducting parts of the samples with much higher n than the average over the whole. I conjecture that the difference between the ceramic and macrocrystalline samples may be connected with a larger effect of defects and disorder on charge density waves than on superconductivity.

While I appreciate the careful studies of single crystals in [1, 2], I was disappointed that, at the time of writing of their papers, the authors were apparently unaware of our earlier work

indicating superconductivity at much lower carrier concentrations in a ceramic sample of Zr-doped $SrTO_3$.

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